

STN878

Medium current, high performance, low voltage NPN transistor

Features

- Very low Collector to Emitter saturation voltage
- D.C. Current gain, h_{FE} >100
- 5A continuous collector current
- SOT-223 plastic package for surface mounting circuits
- Available in tape & reel packing

Applications

- Power management in portable equipment
- Voltage regulation in bias supply circuits
- Switching regulator in battery charger applications
- Heavy load driver



The device is manufactured in low voltage PNP planar technology with "base island" layout. the resulting transistor shows exceptional high gain performance coupled with very low saturation voltage.

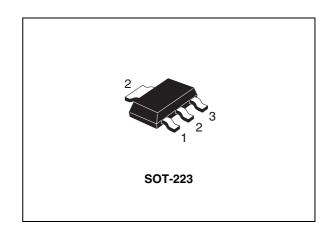


Figure 1. Internal schematic diagram

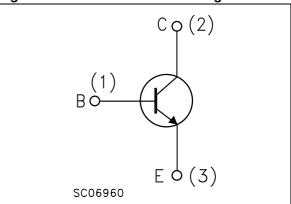


Table 1. Device summary

Order code	Marking	Package	Packaging
STN878	N878	SOT-223	Tape & reel

Contents STN878

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STN878 Electrical ratings

1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	45	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	30	V
V _{EBO}	Emitter-base voltage (I _C = 0)	6	V
I _C	Collector current	5	Α
I _{CM}	Collector peak current (t _P < 5ms)	10	Α
P _{tot}	Total dissipation at T _{amb} = 25°C	1.6	W
T _{stg}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-amb}	Thermal resistance junction-amb ⁽¹⁾ max	78	°C/W

^{1.} Device mounted on PCB area of 1 cm².

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Electrical characteristics STN878

2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$

Table 4. Electrical characteristics

Symbol	Parameter	Test co	nditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E =0)	$V_{CB} = 30 \text{ V}$ $V_{CB} = 30 \text{ V}$;	T _C = 100 °C			10 100	μ Α μ Α
I _{EBO}	Emitter cut-off current (I _C =0)	V _{EB} = 6 V				10	μΑ
V _{(BR)CEO} (1)	Collector-emitter breakdown voltage (I _B =0)	I _C = 10 mA		30			V
V _{(BR)CBO}	Collector-base breakdown voltage (I _E =0)	I _C = 100 μA		45			V
V _{(BR)EBO}	Emitter-base breakdown voltage (I _C =0)	I _E = 100 μA		6			V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	· ·	$I_B = 5 \text{ mA}$ $I_B = 50 \text{ mA}$ $I_B = 0.25 \text{ A}$ $I_B = 0.25 \text{ A}$ $I_B = 0.4 \text{ A}$ $I_B = 0.5 \text{ A}$		0.7 1 1.2	0.15 0.35 0.7	V V V V
V _{BE(sat)} (1)	Base-emitter saturation voltage	$I_C = 2 A$ $I_C = 6 A$	$I_B = 50 \text{ mA}$ $I_B = 0.25 \text{ A}$		1.2	1.1	V V
h _{FE} ⁽¹⁾	DC current gain	_	$V_{CE} = 1 V$	120 100 70	200 200 100 100 55 35	300	
t _d t _r t _s t _f	Resistive load Delay time Rise time Storage time Fall time	$I_C = 3 A$ $I_{B1} = -I_{B2} = 60$ see <i>Figure 8</i>	• •		180 160 250 80	220 210 300 100	ns ns ns

^{1.} Pulsed duration = 300 ms, duty cycle \leq 1.5 %

2.1 Electrical characteristics (curves)

Figure 2. DC current gain

Figure 3. DC current gain

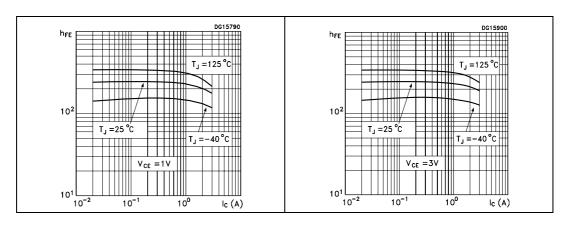


Figure 4. Collector-emitter saturation voltage

Figure 5. Base-emitter saturation voltage

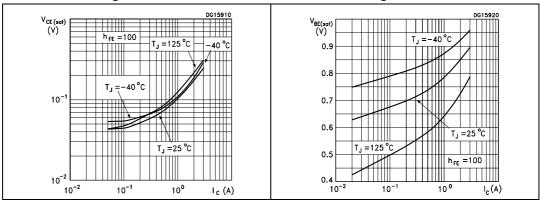
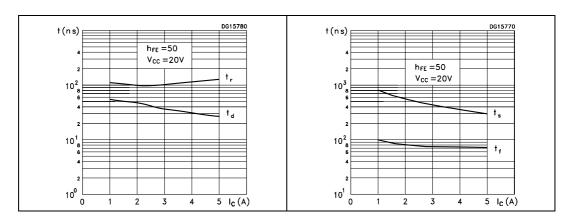


Figure 6. Switching time resistive load Figure 7. Switching time resistive load

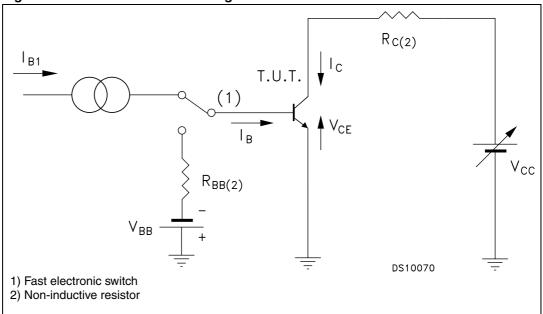


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2.2 Test circuits

Figure 8. Resistive load switching test circuit



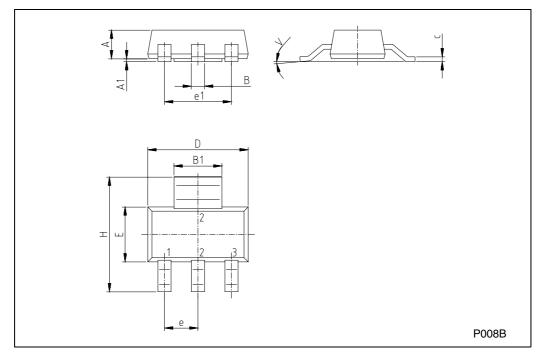
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

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SOT-223 MECHANICAL DATA

DIM.	mm			inch		
J	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α			1.80			0.071
В	0.60	0.70	0.80	0.024	0.027	0.031
B1	2.90	3.00	3.10	0.114	0.118	0.122
С	0.24	0.26	0.32	0.009	0.010	0.013
D	6.30	6.50	6.70	0.248	0.256	0.264
е		2.30			0.090	
e1		4.60			0.181	
E	3.30	3.50	3.70	0.130	0.138	0.146
Н	6.70	7.00	7.30	0.264	0.276	0.287
V			10°			10°
A1		0.02				



STN878 Revision history

4 Revision history

Table 5. Document revision history

	Date	Revision	Changes
Ī	21-Aug-2007	1	Initial release.

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